APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention

High Voltage Circuits Implemented Using Low Voltage Transistors

Application Type: regular, utility

Attorney Docket Number: TI-37611

Correspondence address:

Customer Number: 23494

Inventor Information:

Inventor 1:

Applicant Authority Type: Inventor

Citizenship: IN
Name prefix: Mr.

Given Name: Sanish
Middle Name: Koshi
Family Name: JACOB

Residence:

City of Residence: Trivandrum

Country of Residence: IN

Address-1 of Mailing Address: 8-H, Saraswathi Nilayam

Address-2 of Mailing Address: Jawahar Nagar
City of Mailing Address: Trivandrum

State of Mailing Address:

Postal Code of Mailing Address: 695 041

Country of Mailing Address: IN

Phone: (972) 917-4371 **Fax:** (972) 917-4418

E-mail:

Attorney Information:

practitioner(s) at Customer Number:

23494



as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.

Publication Information:
Suggested Figure for Publication Suggested Classification Suggested Technology Center Total Number of Drawing Sheets - 20

Assignee 1:

Organization Name: Texas Instruments Incorporated

Address-1 of Mailing Address: P. O. Box 655474

Address-2 of Mailing Address:MS 3999City of Mailing Address:DallasState of Mailing Address:TXPostal Code of Mailing Address:75265Country of Mailing Address:US

Phone: (972) 917-4371 **Fax:** (972) 917-4418

E-mail: